

Fast CMOS 3.3V 8-Bit Buffer/Line Driver

Features

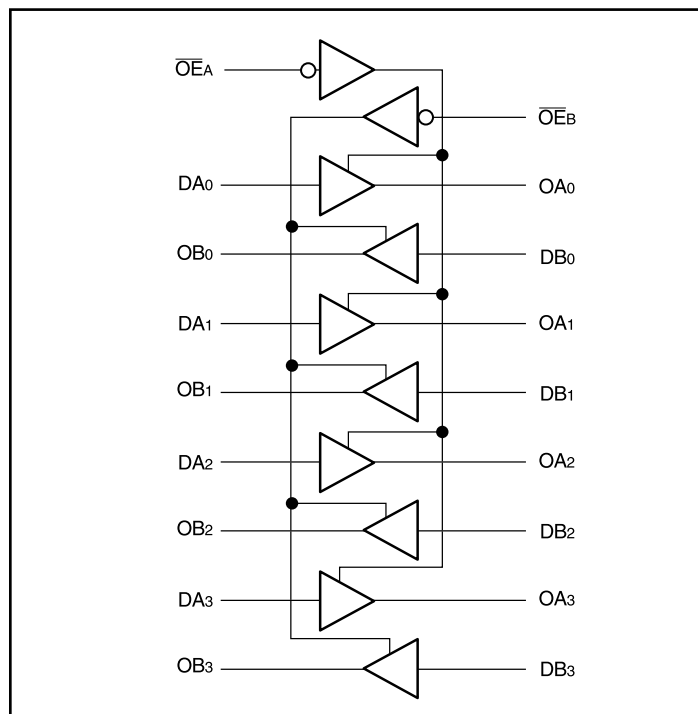
- Compatible with LCX™ and LVT™ families of products
- Supports 5V Tolerant Mixed Signal Mode Operation
 - Input can be 3V or 5V
 - Output can be 3V or connected to 5V bus
- Advanced Low Power CMOS Operation
- Excellent output drive capability:
Balanced drives (24 mA sink and source)
- Low ground bounce outputs
- Hysteresis on all inputs
- Industrial operating temperature range: -40°C to +85°C
- Packages (Pb-free & Green available):
 - 20-pin 173-mil wide plastic TSSOP (L)
 - 20-pin 150-mil wide plastic QSOP (Q)
 - 20-pin 300-mil wide plastic SOIC (S)

Description

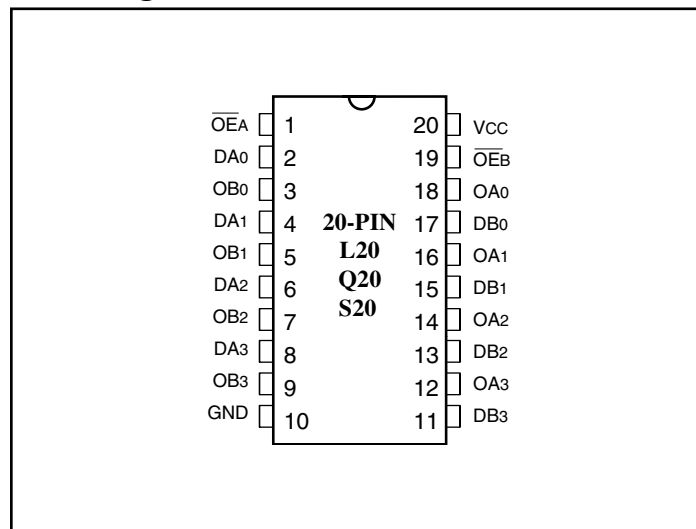
Pericom Semiconductor's PI74LPT244 is an 8-bit buffer/line driver designed for driving high capacitive memory loads. With its balanced-drive characteristics, this high-speed, low power device provides lower ground bounce, transmission line matching of signals, fewer line reflections and lower EMI and RFI effects. This makes it ideal for driving on-board buses and transmission lines.

The PI74LPT244 can be driven from either 3.3V or 5.0V devices allowing this device to be used as a translator in a mixed 3.3/5.0V system.

Block Diagram



Pin Configuration



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-55°C to +125°C
Ambient Temperature with Power Applied	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only)	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	-0.5V to +7.0V
DC Input Voltage	-0.5V to +7.0V
DC Output Current.....	120 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Pin Description

Pin Name	Description
$\overline{OE}_A, \overline{OE}_B$	3-State Output Enable Inputs (Active LOW)
Dxx	Inputs
Oxx	Outputs
GND	Ground
VCC	Power

Truth Table⁽¹⁾

Inputs			Outputs
\overline{OE}_A	\overline{OE}_B	Dxx	Oxx
L	L	L	H
L	L	H	L
H	H	X	Z

Note:

1. H = High Voltage Level, X = Don't Care,
L = Low Voltage Level, Z = High Impedance

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 2.7\text{V}$ to 3.6V)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
V_{IH}	Input HIGH Voltage (Input pins)	Guaranteed Logic HIGH Level		2.2		5.5	V
	Input HIGH Voltage (I/O pins)			2.0		5.5	
V_{IL}	Input LOW Voltage (Input and I/O pins)	Guaranteed Logic LOW Level		-0.5		0.8	
I_{IH}	Input HIGH Current (Input pins)	$V_{CC} = \text{Max.}$	$V_{IN} = 5.5\text{V}$			± 1	μA
	Input HIGH Current (I/O pins)	$V_{CC} = \text{Max.}$	$V_{IN} = V_{CC}$			± 1	
I_{IL}	Input LOW Current (Input pins)	$V_{CC} = \text{Max.}$	$V_{IN} = \text{GND}$			± 1	
	Input LOW Current (I/O pins)	$V_{CC} = \text{Max.}$	$V_{IN} = \text{GND}$			± 1	
I_{OZH}	High Impedance Output Current	$V_{CC} = \text{Max.}$	$V_{OUT} = 5.5\text{V}$			± 1	
I_{OZL}	(3-State Output pins)	$V_{CC} = \text{Max.}$	$V_{OUT} = \text{GND}$			± 1	
V_{IK}	Clamp Diode Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18\text{ mA}$			-0.7	-1.2	V
I_{ODH}	Output HIGH Current	$V_{CC} = 3.3\text{V}, V_{IN} = V_{IH}$ or $V_{IL}, V_O = 1.5\text{V}^{(3)}$		-36	-60	-110	mA
I_{ODL}	Output LOW Current	$V_{CC} = 3.3\text{V}, V_{IN} = V_{IH}$ or $V_{IL}, V_O = 1.5\text{V}^{(3)}$		50	90	200	
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -0.1\text{ mA}$	$V_{CC} - 0.2$			V
			$I_{OH} = -3\text{ mA}$	2.4	3.0		
		$V_{CC} = 3.0\text{V},$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -8\text{ mA}$	2.4 ⁽⁵⁾	3.0		
			$I_{OH} = -24\text{ mA}$	2.0			
V_{OL}	Output LOW Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 0.1\text{ mA}$			0.2	
			$I_{OL} = 16\text{ mA}$		0.2	0.4	
			$I_{OL} = 24\text{ mA}$		0.3	0.5	
I_{OS}	Short Circuit Current ⁽⁴⁾	$V_{CC} = \text{Max.}^{(3)}, V_{OUT} = \text{GND}$		-60	-85	-240	mA
I_{OFF}	Power Down Disable	$V_{CC} = 0\text{V}, V_{IN}$ or $V_{OUT} \leq 4.5\text{V}$				± 100	μA
V_H	Input Hysteresis				150		mV

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- This parameter is guaranteed but not tested.
- $V_{OH} = V_{CC} - 0.6\text{V}$ at rated current.

Capacitance ($T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$)

Parameters ⁽¹⁾	Description	Test Conditions	Typ	Max.	Units
C_{IN}	Input Capacitance	$V_{IN} = 0V$	4.5	6	pF
C_{OUT}	Output Capacitance	$V_{OUT} = 0V$	5.5	8	

Note:

1. This parameter is determined by device characterization but is not production tested.

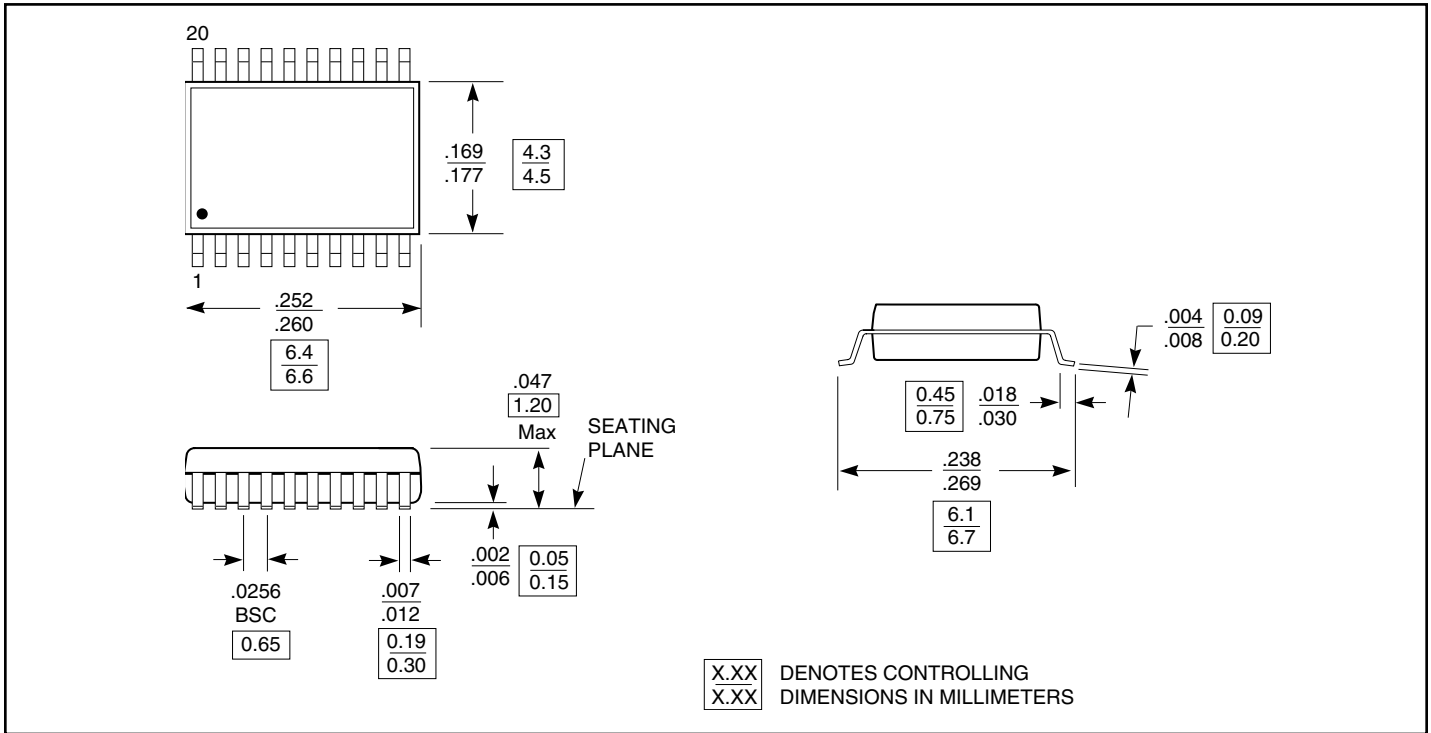
Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ ⁽²⁾	Max.	Units
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$ $V_{IN} = \text{GND}$ or V_{CC}		0.1	10	μA
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = V_{CC}$ $- 0.6V$ ⁽³⁾			500	μA
I_{CCD}	Dynamic Power Supply ⁽⁴⁾	$V_{CC} = \text{Max.}$, Outputs Open $\overline{OE}_X = \text{GND}$ One Bit Toggling 50% Duty Cycle		50	75	$\mu\text{A}/\text{MHz}$
I_C	Total Power Supply Current ⁽⁶⁾	$V_{CC} = \text{Max.}$, Outputs Open $f_i = 10\text{ MHz}$ 50% Duty Cycle $\overline{OE}_X = \text{GND}$ One Bit Toggling		0.6	2.3	mA
		$V_{CC} = \text{Max.}$, Outputs Open $f_i = 2.5\text{ MHz}$ 50% Duty Cycle $\overline{OE}_X = \text{GND}$ 8 Bits Toggling		2.1	4.7 ⁽⁵⁾	

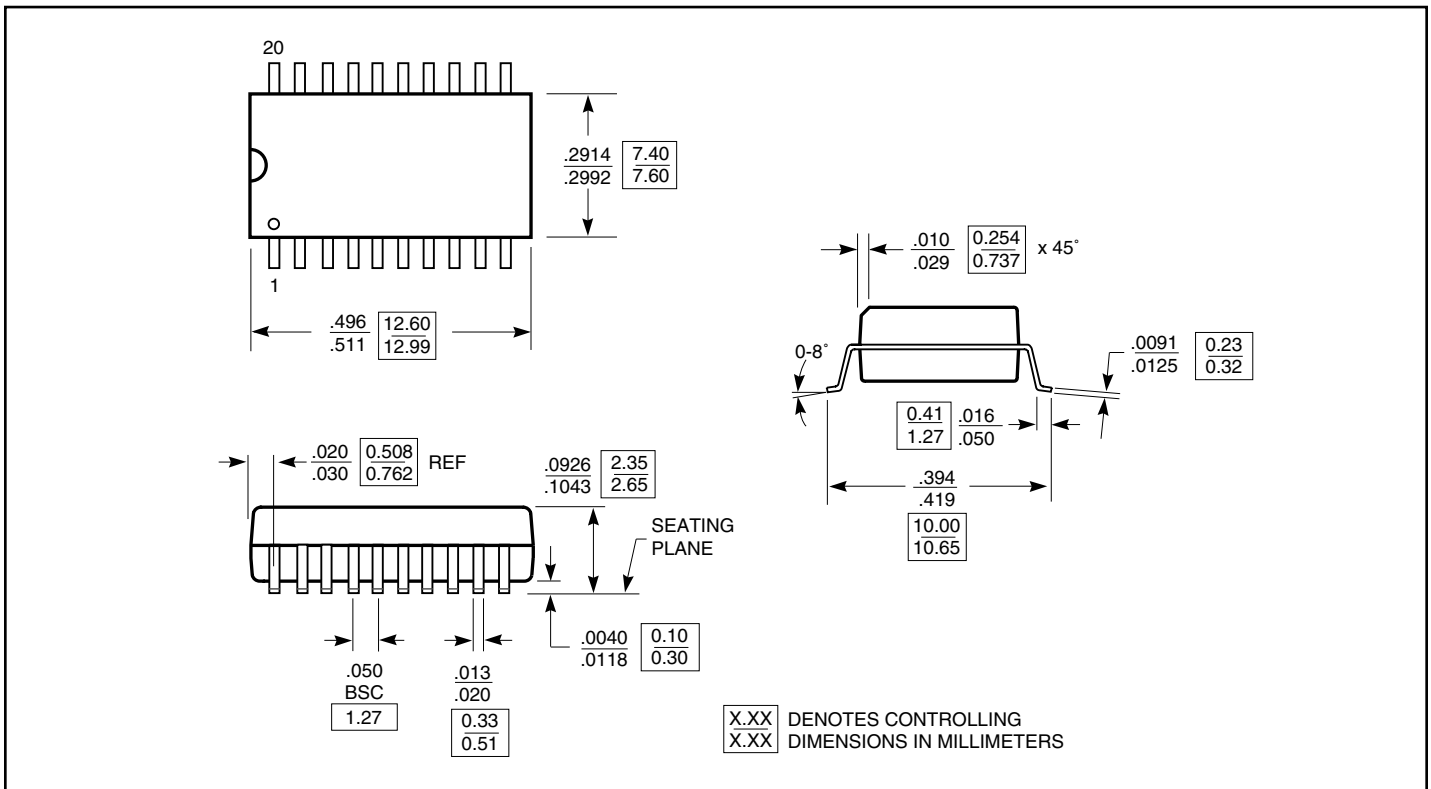
Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at $V_{CC} = 3.3V$, $+25^\circ\text{C}$ ambient.
3. Per TTL driven input; all other inputs at V_{CC} or GND .
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$
 $I_{CC} = \text{Quiescent Current (} I_{CCL}, I_{CCH} \text{ and } I_{CCZ} \text{)}$
 $\Delta I_{CC} = \text{Power Supply Current for a TTL High Input}$
 $D_H = \text{Duty Cycle for TTL Inputs High}$
 $N_T = \text{Number of TTL Inputs at } D_H$
 $I_{CCD} = \text{Dynamic Current Caused by an Input Transition Pair (HLH or LHL)}$
 $f_{CP} = \text{Clock Frequency for Register Devices (Zero for Non-Register Devices)}$
 $N_{CP} = \text{Number of Clock Inputs at } f_{CP}$
 $f_i = \text{Input Frequency}$
 $N_i = \text{Number of Inputs at } f_i$
 All currents are in milliamperes and all frequencies are in megahertz.

Packaging Mechanical: 20-pin TSSOP (L)



Packaging Mechanical: 20-pin SOIC (S)



Ordering Information

Ordering Code	Package Code	Speed Grade	Description
PI74LPT244Q	Q	Blank	20-pin 150-mil wide plastic QSOP
PI74PLT244QE	Q	Blank	Pb-free & Green 20-pin 150-mil wide plastic QSOP
PI74LPT244S	S	Blank	20-pin 300-mil wide plastic SOIC
PI74LPT244L	L	Blank	20-pin 173-mil wide plastic TSSOP
PI74LPT244AQ	Q	A	20-pin 150-mil wide plastic QSOP
PI74PLT244AQE	Q	A	Pb-free & Green 20-pin 150-mil wide plastic QSOP
PI74PLT244AS	S	A	20-pin 300-mil wide plastic SOIC
PI74PLT244AL	L	A	20-pin 173-mil wide plastic TSSOP
PI74PLT244CQ	Q	C	20-pin 150-mil wide plastic QSOP
PI74PLT244CS	S	C	20-pin 300-mil wide plastic SOIC
PI74PLT244CL	L	C	20-pin 173-mil wide plastic TSSOP
PI74PLT244CQE	Q	C	Pb-free & Green 20-pin 150-mil wide plastic QSOP

Notes:

1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/